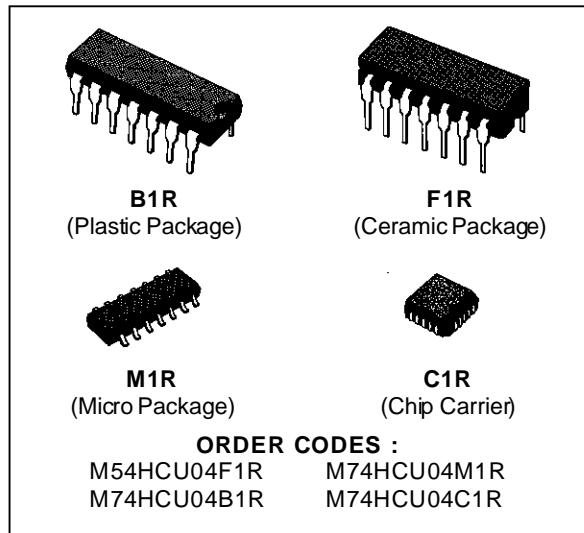


HEX INVERTER (SINGLE STAGE)

- HIGH SPEED
 $t_{PD} = 5 \text{ ns (TYP.)}$ AT $V_{CC} = 5 \text{ V}$
- LOW POWER DISSIPATION
 $I_{CC} = 1 \mu\text{A (MAX.)}$ AT $T_A = 25^\circ\text{C}$
- HIGH NOISE IMMUNITY
 $V_{NIH} = V_{NIL} = 10 \% V_{CC}$ (MIN.)
- OUTPUT DRIVE CAPABILITY
 10 LSTTL LOADS
- SYMMETRICAL OUTPUT IMPEDANCE
 $|I_{OH}| = I_{OL} = 4 \text{ mA (MIN.)}$
- BALANCED PROPAGATION DELAYS
 $t_{PLH} = t_{PHL}$
- WIDE OPERATING VOLTAGE RANGE
 $V_{CC (\text{OPR})} = 2 \text{ V TO } 6 \text{ V}$
- PIN AND FUNCTION COMPATIBLE WITH
 54/74LS04



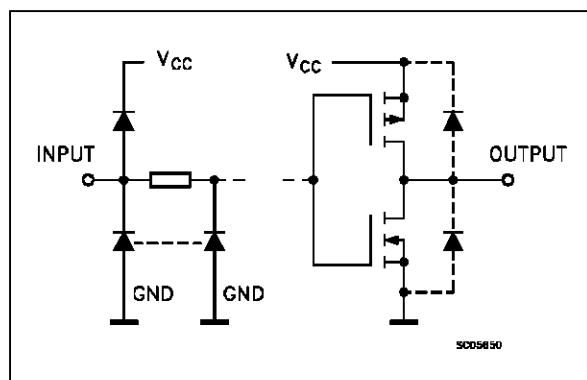
DESCRIPTION

The M54/74HCU04 is a high speed CMOS HEX INVERTER (SINGLE STAGE) fabricated in silicon gate C^2MOS technology. It has the same high speed performance of LSTTL combined with true CMOS low power consumption.

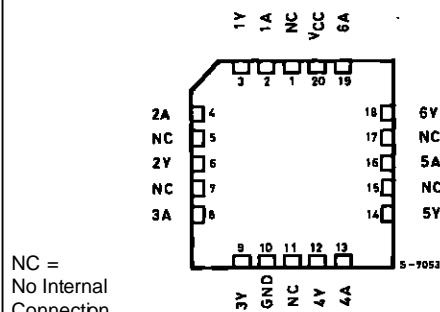
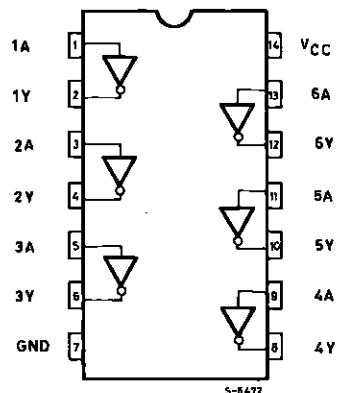
As the internal circuit is composed of a single stage inverter, it can be used in crystal oscillator.

All inputs are equipped with circuits against static discharge and transient excess voltage.

INPUT AND OUTPUT EQUIVALENT CIRCUIT



PIN CONNECTIONS (top view)

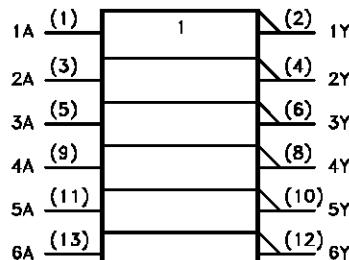


M54/M74HCU04

TRUTH TABLE

A	Y
L	H
H	L

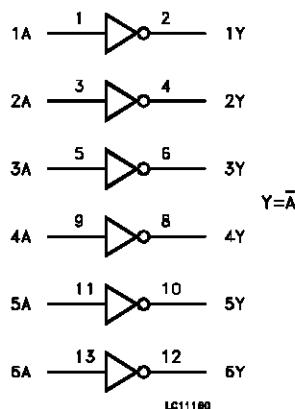
IEC LOGIC SYMBOL



PIN DESCRIPTION

PIN No	SYMBOL	NAME AND FUNCTION
1, 3, 5, 9, 11, 13	1A to 6A	Data Inputs
2, 4, 6, 8, 10, 12	1Y to 6Y	Data Outputs
7	GND	Ground (0V)
14	Vcc	Positive Supply Voltage

LOGIC DIAGRAM



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{CC}	Supply Voltage	-0.5 to +7	V
V_I	DC Input Voltage	-0.5 to $V_{CC} + 0.5$	V
V_O	DC Output Voltage	-0.5 to $V_{CC} + 0.5$	V
I_{IK}	DC Input Diode Current	± 20	mA
I_{OK}	DC Output Diode Current	± 20	mA
I_O	DC Output Source Sink Current Per Output Pin	± 25	mA
I_{CC} or I_{GND}	DC V_{CC} or Ground Current	± 50	mA
P_D	Power Dissipation	500 (*)	mW
T_{STG}	Storage Temperature	-65 to +150	°C
T_L	Lead Temperature (10 sec)	300	°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these condition is not implied.

(*) 500 mW: $\leq 65^\circ\text{C}$ derate to 300 mW by $10\text{mW}/^\circ\text{C}$: 65°C to 85°C

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Value			Unit
V _{CC}	Supply Voltage	2 to 6			V
V _I	Input Voltage	0 to V _{CC}			V
V _O	Output Voltage	0 to V _{CC}			V
T _{op}	Operating Temperature: M54HC Series M74HC Series	-55 to +125 -40 to +85			°C °C
t _r , t _f	Input Rise and Fall Time	V _{CC} = 2 V	0 to 1000		
		V _{CC} = 4.5 V	0 to 500		
		V _{CC} = 6 V	0 to 400		

DC SPECIFICATIONS

Symbol	Parameter	Test Conditions		Value						Unit	
		V _{CC} (V)		T _A = 25 °C 54HC and 74HC			-40 to 85 °C 74HC		-55 to 125 °C 54HC		
				Min.	Typ.	Max.	Min.	Max.	Min.	Max.	
V _{IH}	High Level Input Voltage	2.0 4.5 6.0		1.7			1.7		1.7		V
				3.6			3.6		3.6		
				4.8			4.8		4.8		
V _{IL}	Low Level Input Voltage	2.0 4.5 6.0			0.3		0.3		0.3		V
					0.9		0.9		0.9		
					1.2		1.2		1.2		
V _{OH}	High Level Output Voltage	2.0 4.5 6.0 4.5 6.0	V _I = V _{IH} or V _{IL}	1.8	2.0		1.8		1.8		V
				4.0	4.5		4.0		4.0		
				5.5	5.9		5.5		5.5		
				4.18	4.31		4.13		4.10		
				5.68	5.8		5.63		5.60		
V _{OL}	Low Level Output Voltage	2.0 4.5 6.0 4.5 6.0	V _I = V _{IH} or V _{IL}		0.0	0.2		0.2		0.2	V
					0.0	0.5		0.5		0.5	
					0.1	0.5		0.5		0.5	
					0.17	0.26		0.33		0.40	
					0.18	0.26		0.33		0.40	
I _I	Input Leakage Current	6.0	V _I = V _{CC} or GND			±0.1		±1		±1	µA
I _{CC}	Quiescent Supply Current	6.0	V _I = V _{CC} or GND			1		10		20	µA

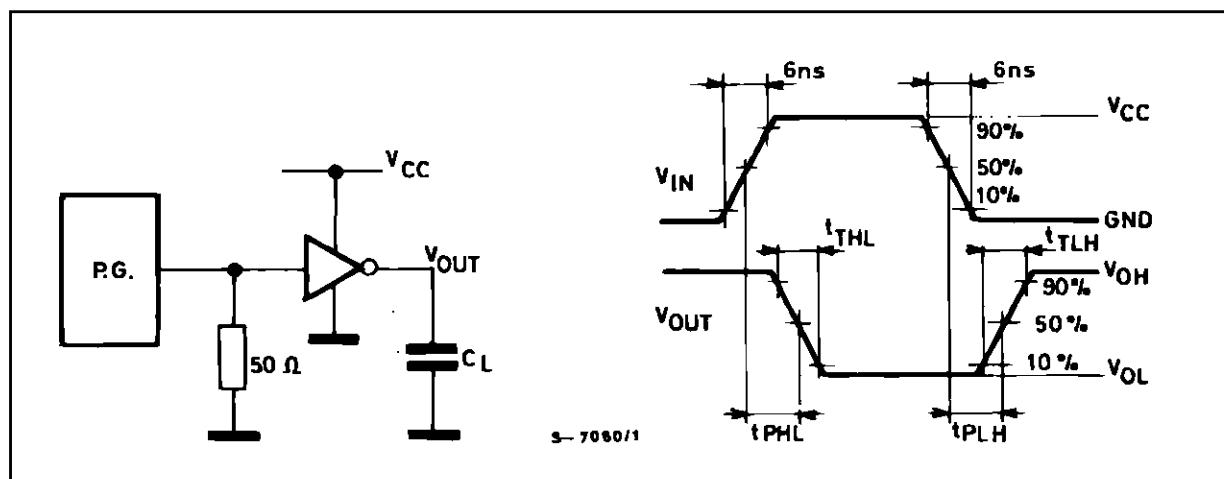
M54/M74HCU04

AC ELECTRICAL CHARACTERISTICS ($C_L = 50 \text{ pF}$, Input $t_r = t_f = 6 \text{ ns}$)

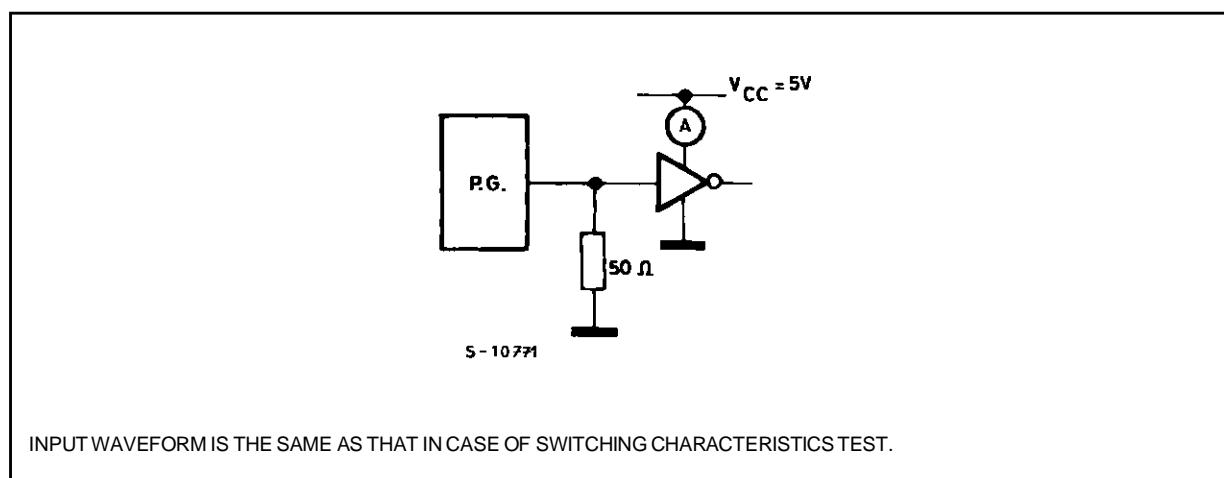
Symbol	Parameter	Test Conditions			Value						Unit
		V _{CC} (V)	$T_A = 25^\circ\text{C}$ 54HC and 74HC			-40 to 85 °C 74HC		-55 to 125 °C 54HC			
			Min.	Typ.	Max.	Min.	Max.	Min.	Max.		
t _{TLH} t _{THL}	Output Transition Time	2.0		30	75		95		110	ns	
		4.5		8	15		19		22		
		6.0		7	13		16		19		
t _{PLH} t _{PHL}	Propagation Delay Time	2.0		18	60		75		90	ns	
		4.5		6	12		15		18		
		6.0		5	10		13		15		
C _{IN}	Input Capacitance			5	15		15		15	pF	
C _{PD} (*)	Power Dissipation Capacitance			13						pF	

(*) C_{PD} is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load.
(Refer to Test Circuit). Average operating current can be obtained by the following equation. I_{cc}(opr) = C_{PD} • V_{CC} • f_{IN} + I_{cc}

SWITCHING CHARACTERISTICS TEST CIRCUIT

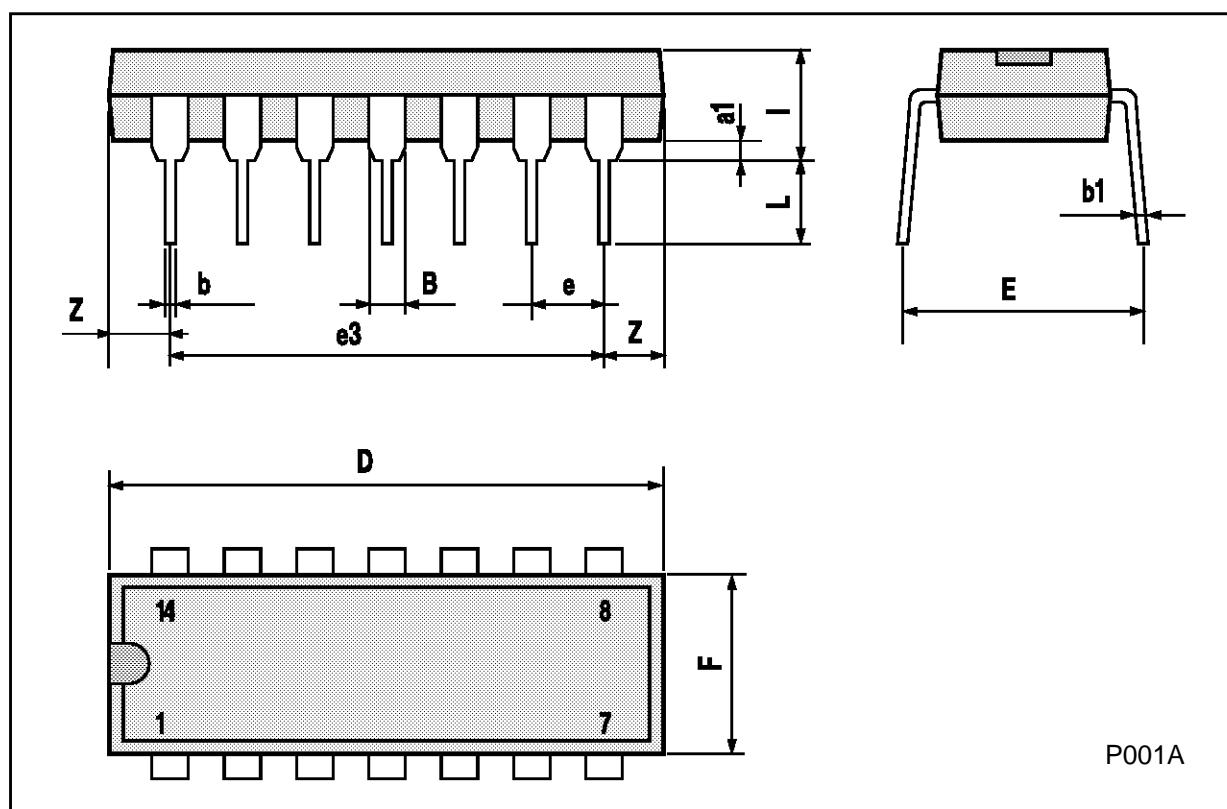


TEST CIRCUIT I_{cc} (Opr.)



Plastic DIP14 MECHANICAL DATA

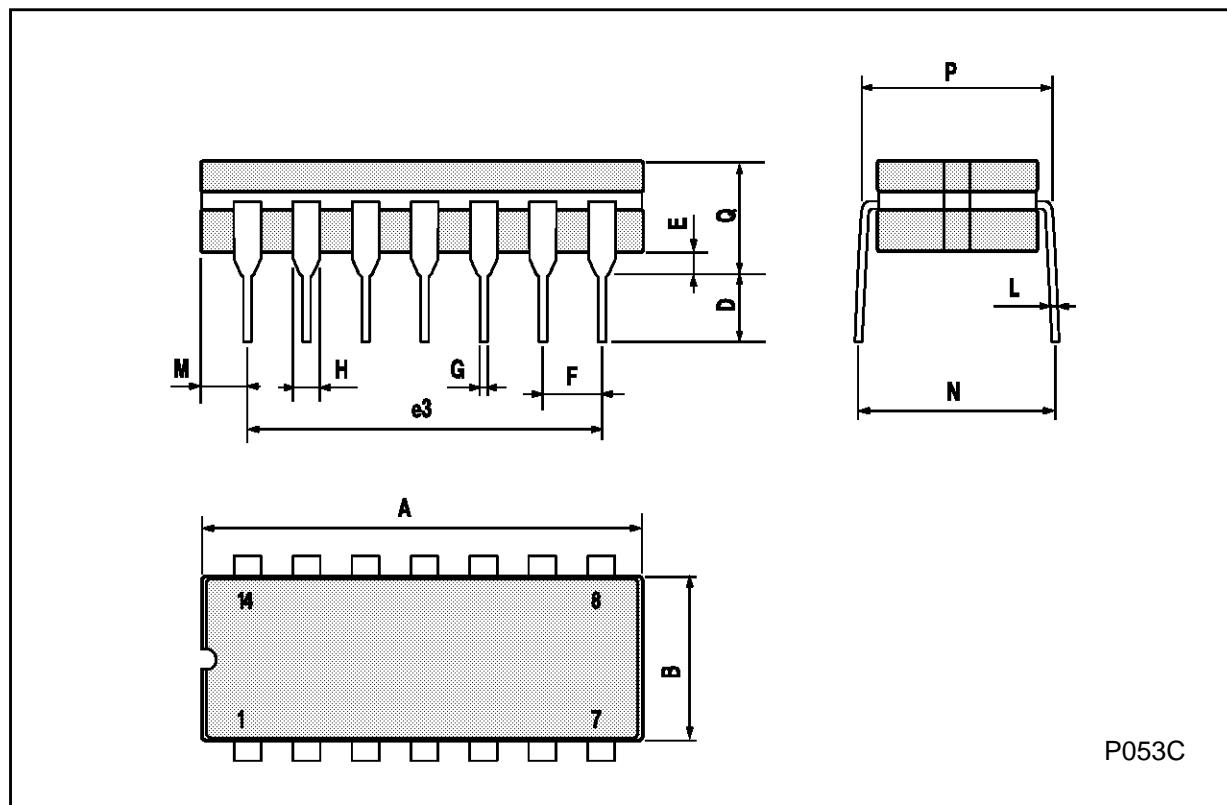
DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
a1	0.51			0.020		
B	1.39		1.65	0.055		0.065
b		0.5			0.020	
b1		0.25			0.010	
D			20			0.787
E		8.5			0.335	
e		2.54			0.100	
e3		15.24			0.600	
F			7.1			0.280
I			5.1			0.201
L		3.3			0.130	
Z	1.27		2.54	0.050		0.100



P001A

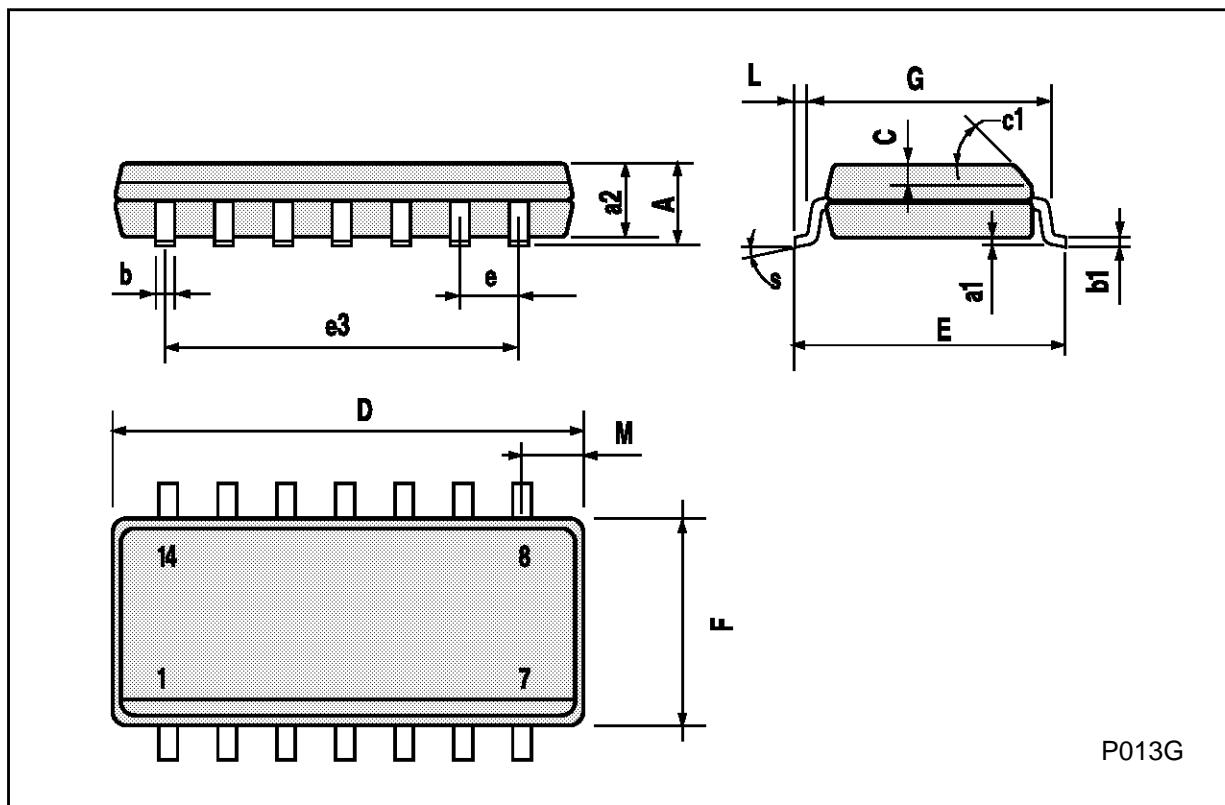
Ceramic DIP14/1 MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A			20			0.787
B			7.0			0.276
D		3.3			0.130	
E	0.38			0.015		
e3		15.24			0.600	
F	2.29		2.79	0.090		0.110
G	0.4		0.55	0.016		0.022
H	1.17		1.52	0.046		0.060
L	0.22		0.31	0.009		0.012
M	1.52		2.54	0.060		0.100
N			10.3			0.406
P	7.8		8.05	0.307		0.317
Q			5.08			0.200



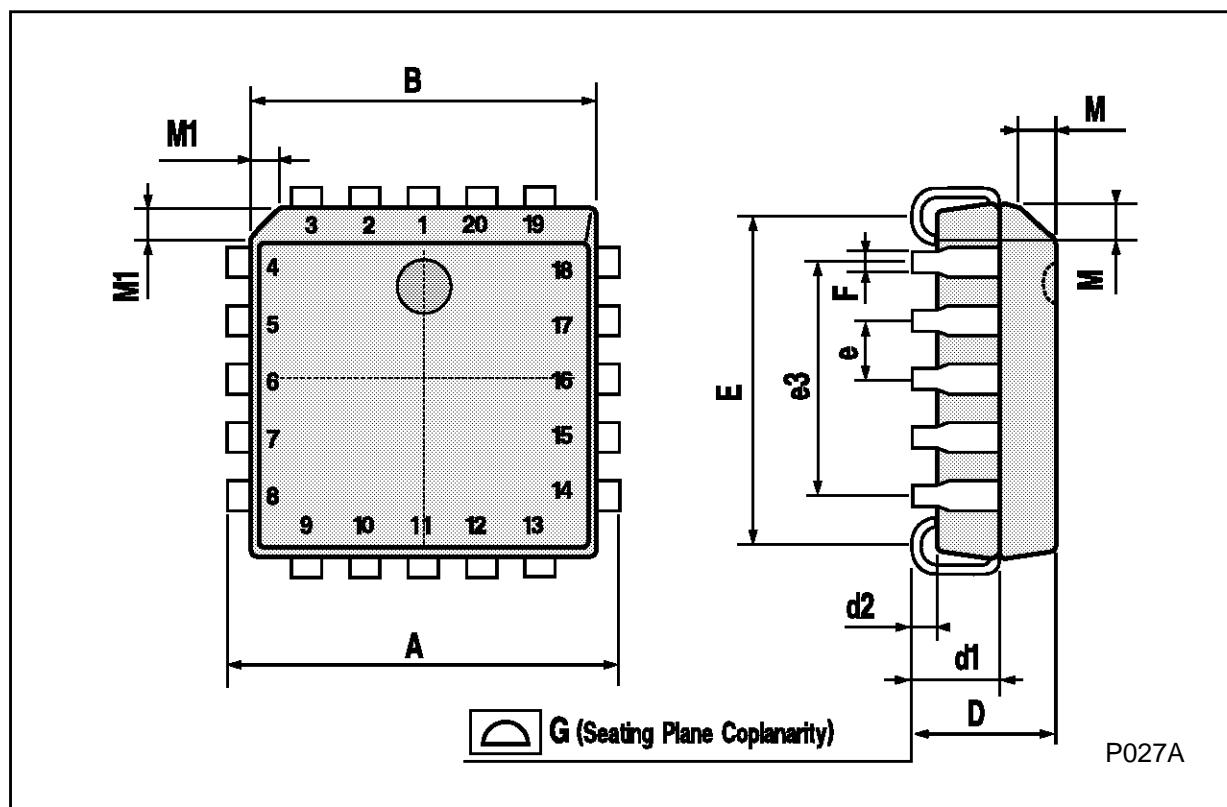
SO14 MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A			1.75			0.068
a1	0.1		0.2	0.003		0.007
a2			1.65			0.064
b	0.35		0.46	0.013		0.018
b1	0.19		0.25	0.007		0.010
C		0.5			0.019	
c1		45° (typ.)				
D	8.55		8.75	0.336		0.344
E	5.8		6.2	0.228		0.244
e		1.27			0.050	
e3		7.62			0.300	
F	3.8		4.0	0.149		0.157
G	4.6		5.3	0.181		0.208
L	0.5		1.27	0.019		0.050
M			0.68			0.026
S		8° (max.)				



PLCC20 MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	9.78		10.03	0.385		0.395
B	8.89		9.04	0.350		0.356
D	4.2		4.57	0.165		0.180
d1		2.54			0.100	
d2		0.56			0.022	
E	7.37		8.38	0.290		0.330
e		1.27			0.050	
e3		5.08			0.200	
F		0.38			0.015	
G			0.101			0.004
M		1.27			0.050	
M1		1.14			0.045	



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